STC03DE170HV

Hybrid emitter switched bipolar transistor
ESBT® 1700V - 3A - 0.33 Ω

Features

$V_{CS(ON)}$	I_C	$R_{CS(ON)}$
1 V	3 A	0.33 Ω

- Low equivalent on resistance
- Very fast-switch, up to 150 kHz
- Squared RBSOA, up to 1700V
- Very low C_{ISS} driven by R_G = 47 Ω

Applications

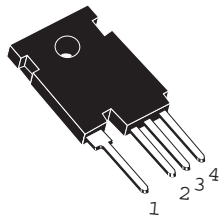
- Aux SMPS for three phase mains

Description

The STC03DE170HV is manufactured in a hybrid structure, using dedicated high voltage Bipolar and low voltage MOSFET technologies, aimed to providing the best performance in ESBT topology. The STC03DE170HV is designed for use in aux flyback smps for any three phase application.

Applications

- Aux SMPS for three phase mains



TO247-4L HV

Figure 1. Internal schematic diagrams

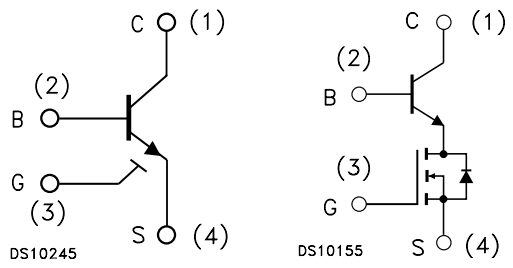


Table 1. Device summary

Order code	Marking	Package	Packaging
STC03DE170HV	C03DE170HV	TO247-4L HV	Tube

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
$V_{CS(SS)}$	Collector-source voltage (V_{BS} =V_{GS} =0V)	1700	V
$V_{BS(OS)}$	Base-source voltage (I_C =0, V_{GS} =0V)	30	V
$V_{SB(OS)}$	Source-base voltage (I_C =0, V_{GS} =0V)	9	V
V_{GS}	Gate-source voltage	± 20	V
I_C	Collector current	3	A
I_{CM}	Collector peak current (t_P < 5ms)	6	A
I_B	Base current	1	A
I_{BM}	Base peak current (t_P < 1ms)	3	A
P_{tot}	Total dissipation at $T_c \leq 25°C$	100	W
T_{stg}	Storage temperature	-40 to 150	°C
T_J	Max. operating junction temperature	125	°C

Table 3. Thermal data

Symbol	Parameter		Value	Unit
$R_{thj-case}$	Thermal resistance junction-case	max	1	°C/W

2 Electrical characteristics

(T_{case} = 25°C unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CS(SS)}$	Collector-source current (V_{BS} =V_{GS} =0V)	$V_{CS(SS)}$ =1700V			100	µA
$I_{BS(OS)}$	Base-source current (I_C =0, V_{GS} =0V)	$V_{BS(OS)}$ =30V			10	µA
$I_{SB(OS)}$	Source-base current (I_C =0, V_{GS} =0V)	$V_{SB(OS)}$ =9V			100	µA
$I_{GS(OS)}$	Gate-source leakage (V_{BS} =0V)	V_{GS} = ± 20V			500	nA
$V_{CS(ON)}$	Collector-source ON voltage	V_{GS} =10V I_C =3A I_B =0.6A V_{GS} =10V I_C =1A I_B =100mA		1 0.3	1.2 0.6	V V
h_{FE}	DC current gain	V_{GS} =10V V_{CS} =1V I_C =3A V_{GS} =10V V_{CS} =1V I_C =1A	 10	5 14		
$V_{BS(ON)}$	Base-source ON voltage	V_{GS} =10V I_C =3A I_B =0.6A V_{GS} =10V I_C =1A I_B =100mA		1 1	1.2	V V
$V_{GS(th)}$	Gate threshold voltage	V_{BS} =V_{GS} I_B =250µA	1.5		3	V
C_{iss}	Input capacitance	V_{CS} =25V f =1MHz V_{GS}=0V		750		pF
$Q_{GS(tot)}$	Gate-source Charge	V_{CS}=15V V_{GS}=10V V_{CB}=0V I_C =4A		12.5		nC
t_s t_f	INDUCTIVE LOAD Storage time Fall time	V_{GS} =10V R_G =47Ω V_{Clamp} =1360V t_p =4µs I_C =3A I_B =0.6A		1000 15		ns ns
t_s t_f	INDUCTIVE LOAD Storage time Fall time	V_{GS} =10V R_G =47Ω V_{Clamp} =1360V t_p =4µs I_C =3A I_B =0.3A		590 15		ns ns
$V_{CS(dyn)}$	Collector-source dynamic voltage (500ns)	V_{CC} =V_{Clamp} =400V V_{GS} =10V I_C =1.5A I_B = 0.1A R_G =47Ω t_{peak} =500ns I_{Bpeak} =3A		9.5		V

Table 4. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{CS(dyn)}$	Collector-source dynamic voltage (1µs)	V_{CC} =V_{Clamp} =400V V_{GS} =10V I_C =1.5A I_B = 0.1A R_G =47Ω t_{peak} =500ns I_{Bpeak} =3A		9.5		V
V_{CSW}	Maximum collector-source voltage switched without snubber	R_G =47Ω h_{FE} =5 I_C = 4A	1700			V

Note (1) Pulsed duration = 300 µs, duty cycle ≤1.5%

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

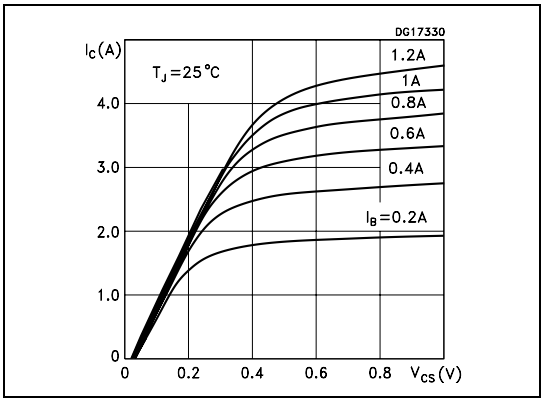


Figure 3. Dynamic collector-source saturation voltage

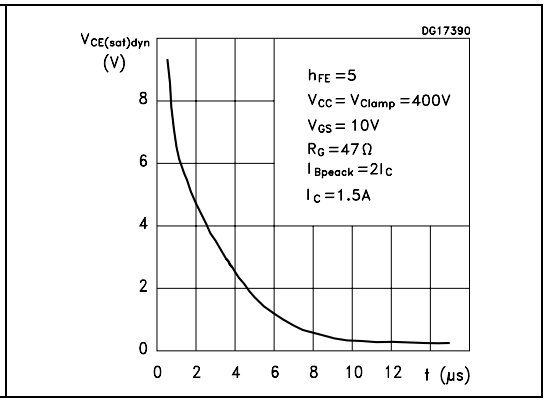


Figure 4. Reverse biased safe operating area

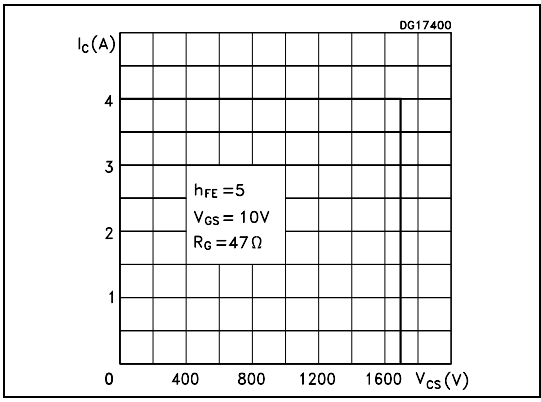


Figure 5. Gate threshold voltage vs temperature

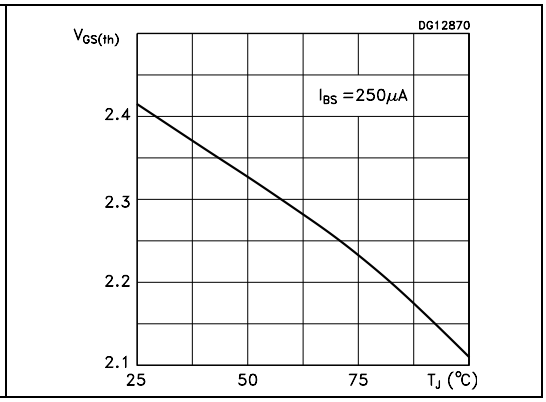


Figure 6. DC current gain

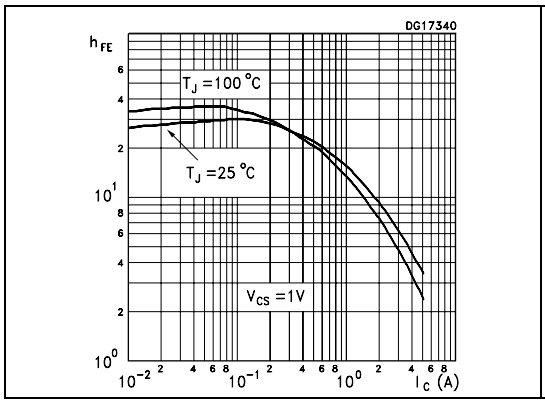


Figure 7. Collector-source On voltage

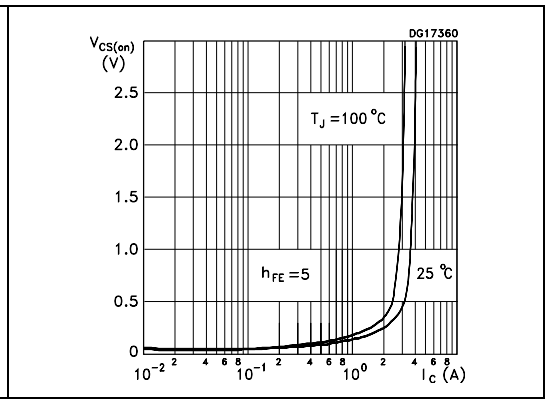


Figure 8. Collector-source On voltage

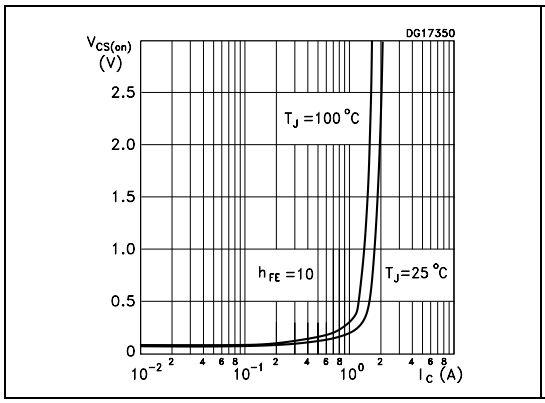


Figure 9. Base-source On voltage

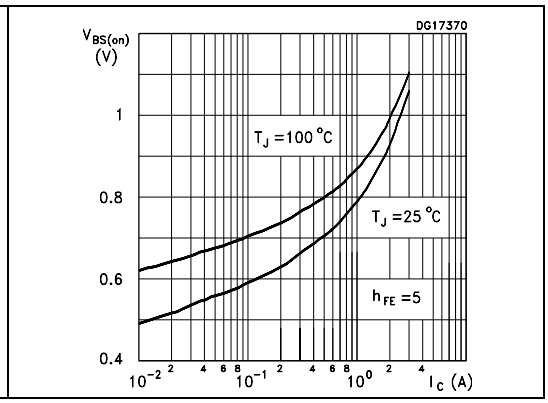


Figure 10. Inductive load switching time

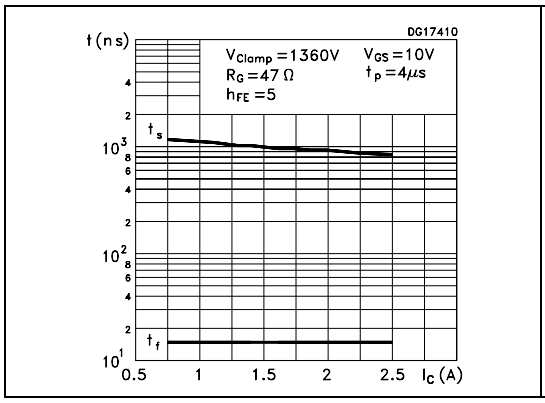
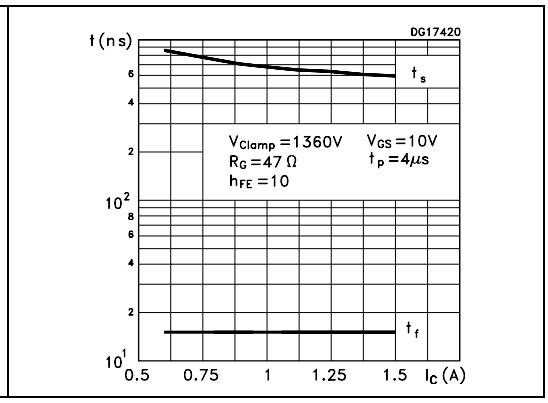


Figure 11. Inductive load switching time

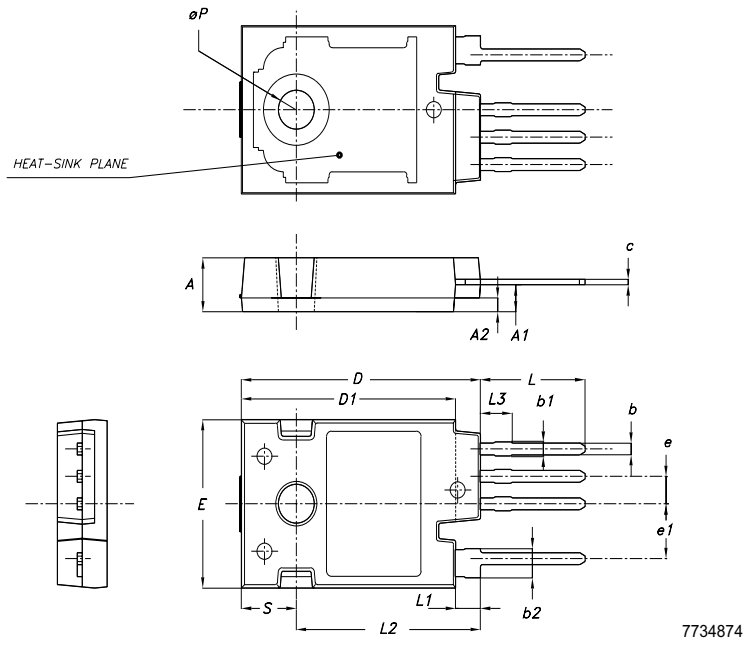


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO247-4L HV MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.85		5.15
A1	2.20	2.50	2.60
A2		1.27	
b	0.95	1.10	1.30
b2	2.50		2.90
c	0.40		0.80
D	23.85	24	24.15
D1		21.50	
E	15.45	15.60	15.75
e	2.54		
e1	5.08		
L	10.20		10.80
L1	2.20	2.50	2.80
L2		18.50	
L3		3	
øP	3.55		3.65
S		5.50	



4 Revision history

Table 5. Revision history

Date	Revision	Changes
26-Sep-2006	1	First release.
12-Jul-2007	2	Improved electrical specification. Updated figures: 2,3,4,6,7,8,9,10 and 11.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries (“ST”) reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST’s terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST’S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS “AUTOMOTIVE GRADE” MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER’S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com